

Technical Data Green Products

Data Sheet N1063, Rev. -

84CNQ035/84CNQ040/84CNQ045 SCHOTTKY RECTIFIER

Applications:

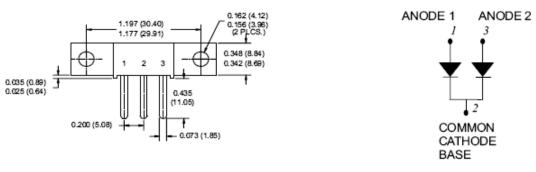
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

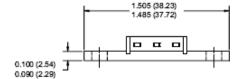
Features:

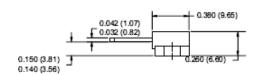
- 125℃ T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- . Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches / mm







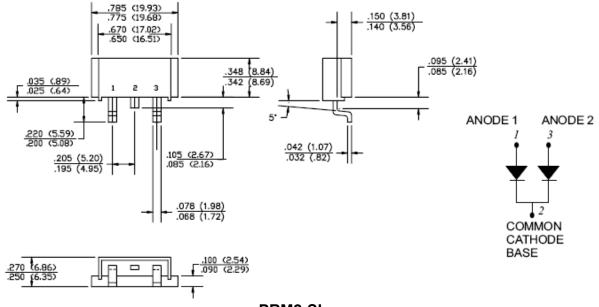
PRM₂

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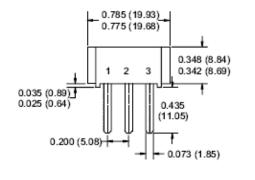


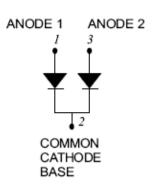


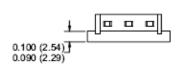
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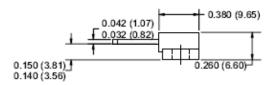


PRM2-SL









PRM2-SM

MARKING, MOLDING RESIN

Marking for 84CNQ035/SL/SM, 1^{st} row SS YYWWL, 2^{nd} row 84CNQ035/SL/SM, 3^{rd} row 1 2 3 (pin) Where YY is the manufacture year

WW is the manufacture week code L is the wafer's Lot Number

Molding resin

Epoxy resin UL: 94V-0

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Ordering Information:

Device	Package	Terminals finish	Shipping
84CNQ035	PRM2	Nickel plated	48pcs / box
84CNQ035S	PRM2	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box
84CNQ035SL	PRM2-SL	Pure Sn plated	100pcs / box
84CNQ035SM	PRM2-SM	Nickel plated	48pcs / box
84CNQ035SMS	PRM2-SM	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box
84CNQ040	PRM2	Nickel plated	48pcs / box
84CNQ040S	PRM2	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box
84CNQ040SL	PRM2-SL	Pure Sn plated	100pcs / box
84CNQ040SM	PRM2-SM	Nickel plated	48pcs / box
84CNQ040SMS	PRM2-SM	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box
84CNQ045	PRM2	Nickel plated	48pcs / box
84CNQ045S	PRM2	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box
84CNQ045SL	PRM2-SL	Pure Sn plated	100pcs / box
84CNQ045SM	PRM2-SM	Nickel plated	48pcs / box
84CNQ045SMS	PRM2-SM	Pure Sn dipped (dipped height 6-8 mm)	48pcs / box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	35 (84CNQ035) 40 (84CNQ040) 45 (84CNQ045)	٧
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _C =91°C, rectangular wave form	80	Α
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	750	Α
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25℃,I _{AS} =8A,L=1.7mH	54	mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5 $\times V_R$ typical	8	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V_{F1}	@ 40A, Pulse, T _J = 25 °C	0.43	0.49	V
(per leg) *	V F1	@ 80A, Pulse, T _J = 25 °C	0.52	0.62	V
	V	@ 40A, Pulse, T _J = 125 °C	0.38	0.44	V
	V_{F2}	@ 80A, Pulse, T _J = 125 °C	0.49	0.60	V
Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R T_J = 25 ^{\circ}\text{C}$	1.5	5	mA
	I _{R2}	$@V_R$ = rated V_R T_J = 125 °C	600	800	mA
Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	2100	2600	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	5.5	-	nΗ
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

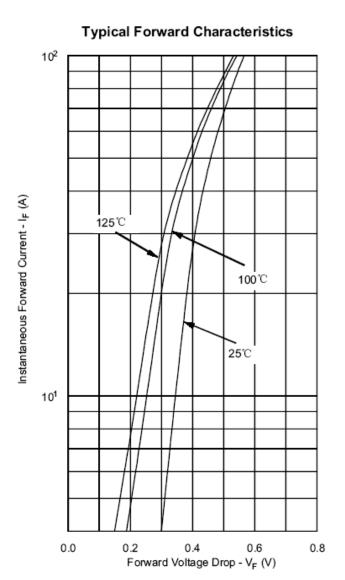
Thermal-Mechanical Specifications:

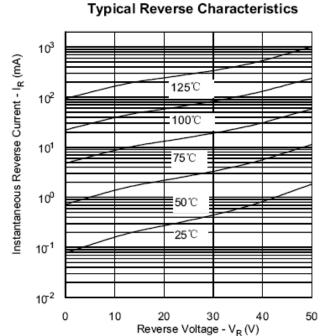
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +125	°C
Storage Temperature	T _{stg}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case(per leg)	$R_{ heta JC}$	DC operation	0.85	°C/W
Typical Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.42	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.30	°C/W
Approximate Weight	wt	-	7.8	g
Mounting Torque	Тм	_	40(min)	Kg-cm
I wounting rorque	I M	-	58(max)	TNg-CITI
Case Style		PRM2 PRM2-SL PRM2	2-SM	·

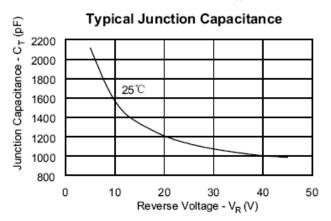
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84CNQ SERIES

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